



2SA1481/2SC2960

High-Speed Switching Applications

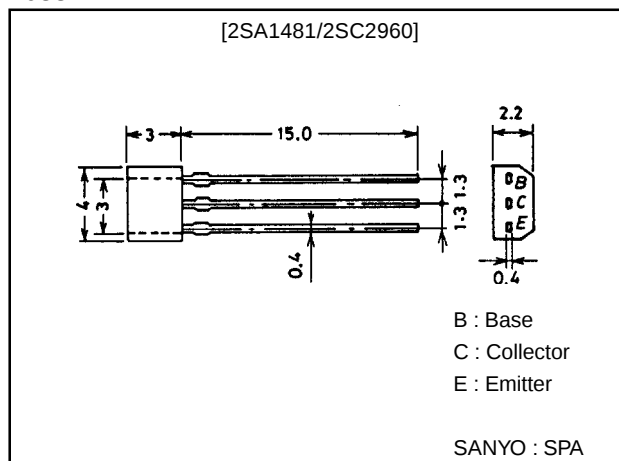
Features

- Fast switching speed.
- High breakdown voltage.

Package Dimensions

unit:mm

2033



() : 2SA1481

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		(-)60	V
Collector-to-Emitter Voltage	V_{CEO}		(-)50	V
Emitter-to-Base Voltage	V_{EBO}		(-)5	V
Collector Current	I_C		(-)150	mA
Peak Collector Current	I_{CP}		(-)400	mA
Collector Dissipation	P_C		250	mW
Junction Temperature	T_J		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

Electrical Characteristic at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)400V, I_E=0$			(-)0.1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)4V, I_C=0$			(-)0.1	μA
DC Current Gain	h_{FE}	$V_{CE}=(-)6V, I_C=(-)1mA$	100*		560*	
Gain-Bandwidth Product	f_T	$V_{CE}=(-)6V, I_C=(-)1mA$		100		MHz
Output Capacitance	C_{ob}	$V_{CB}=(-)6V, f=1MHz$		2.7		pF
				(4.0)		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)10mA, I_B=(-)1mA$		(-)0.1	(-)0.4	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)10mA, I_B=(-)1mA$		(-)0.75	(-)1.1	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-)60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-)50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$	(-)5			V
Delay Time	t_d	See specified Test Circuit		40	60	ns
Rise Time	t_r	See specified Test Circuit		80	130	ns
				(120)	(230)	ns
Storage Time	t_{stg}	See specified Test Circuit		230	450	ns
				(190)	(700)	ns
Fall Time	t_f	See specified Test Circuit		160	250	ns
				(240)	(390)	ns

* ; The 2SA1481/2SC2960 are classified by 1mA h_{FE} as follows :

100	E	200	160	F	320	280	G	560
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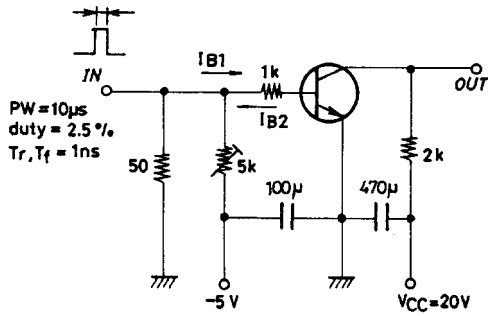
SANYO Electric Co.,Ltd. Semiconductor Business Headquarters

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

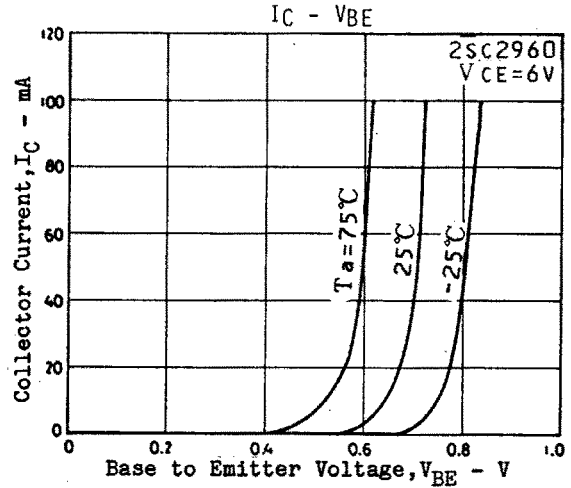
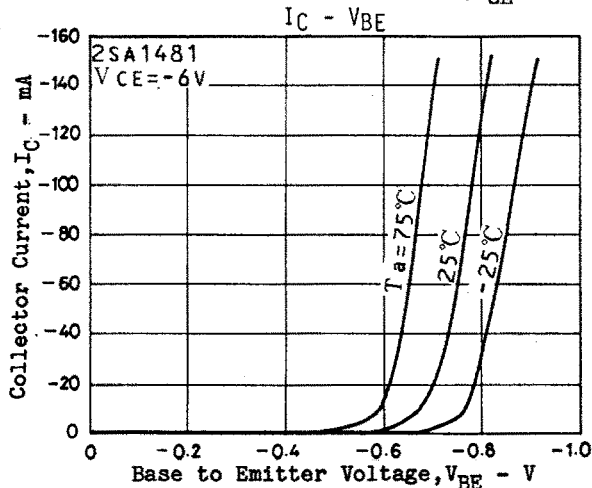
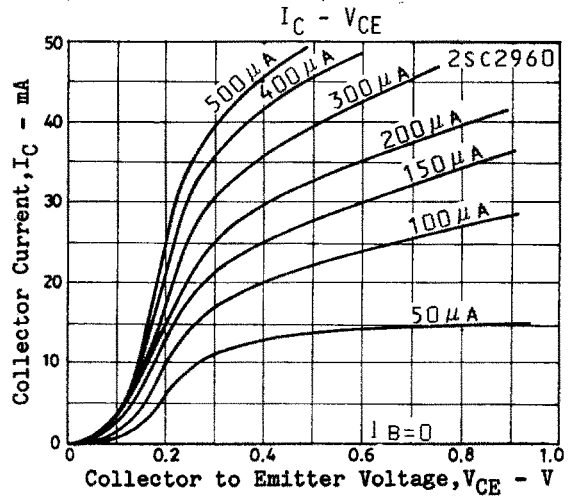
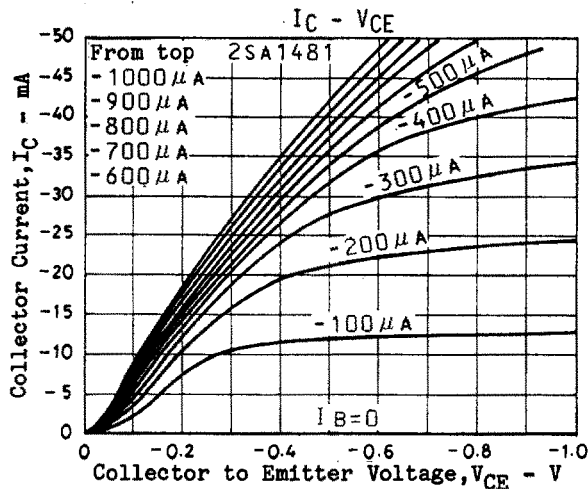
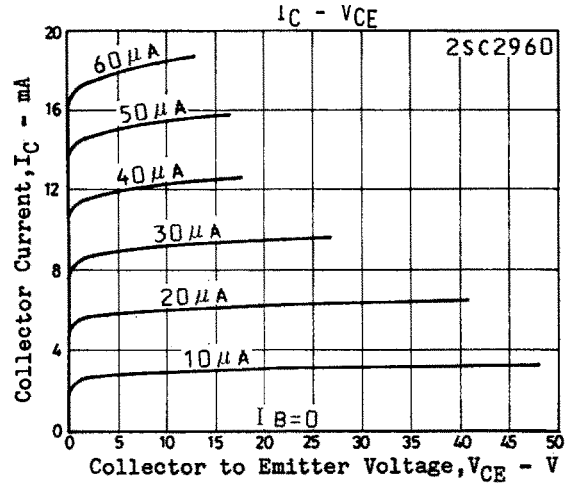
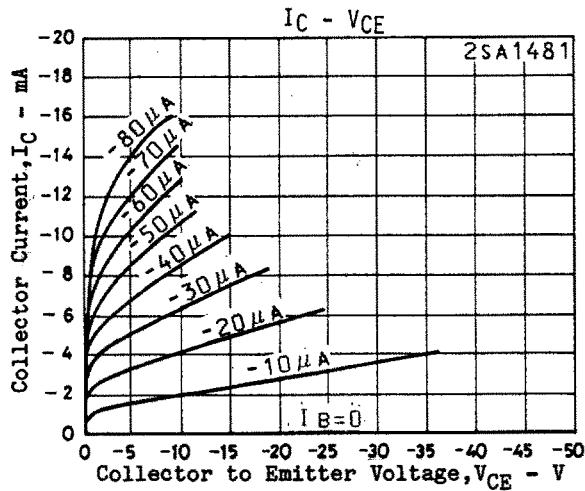
71598HA (KT)/4231MH, 4097TA, TS No.829-1/4

Switching Time Test Circuit

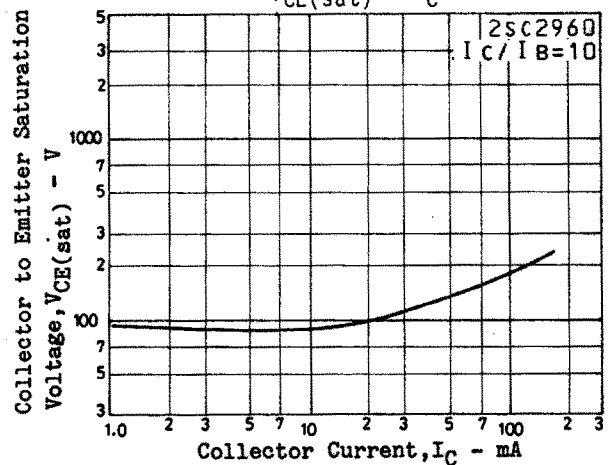
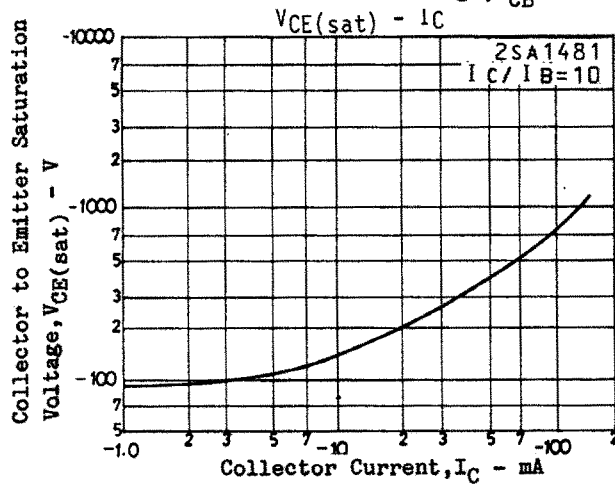
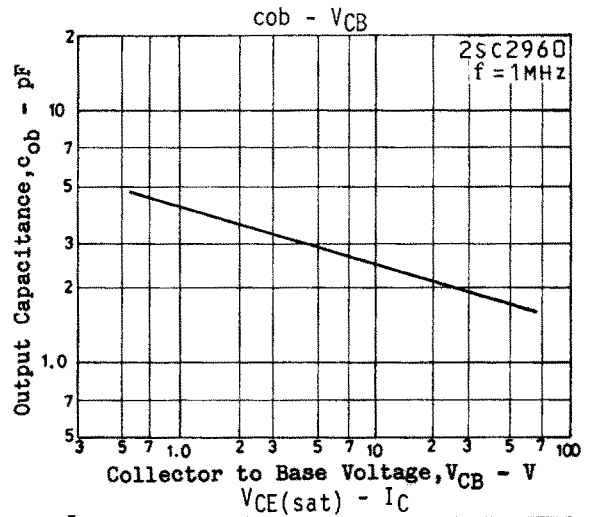
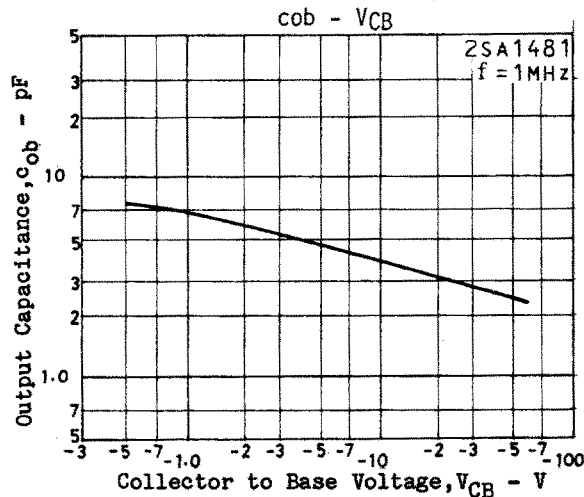
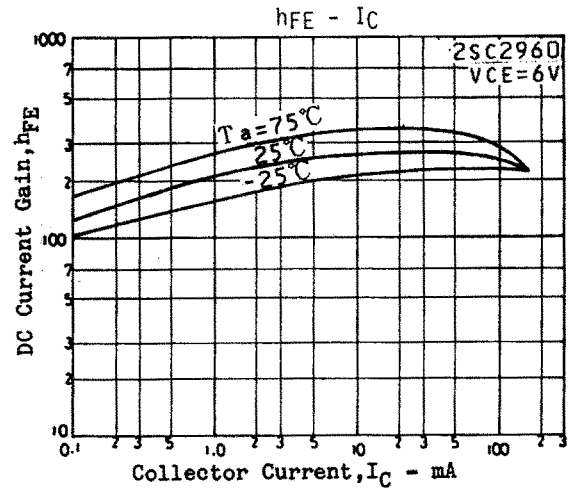
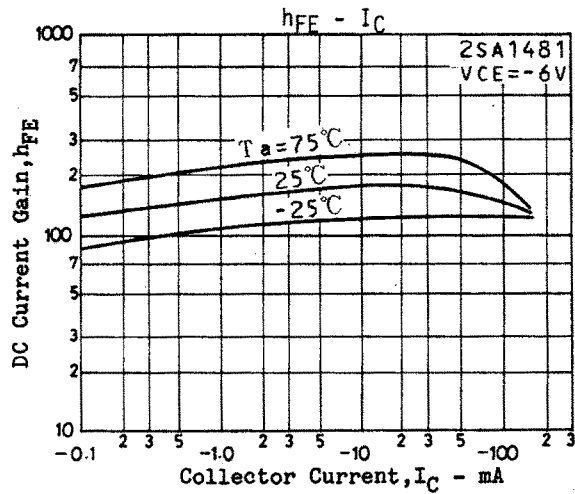
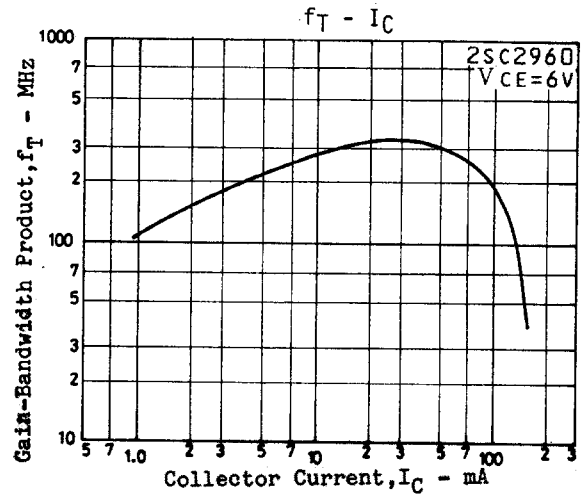
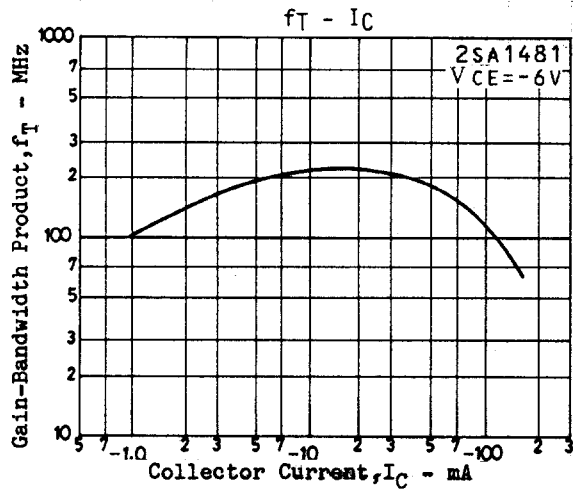
(For PNP, the polarity is reversed.)



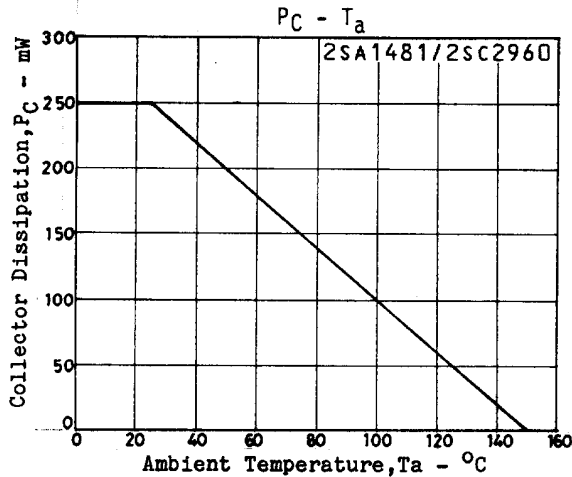
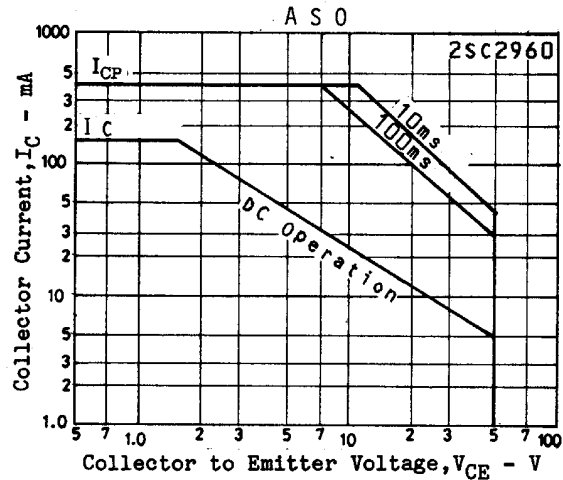
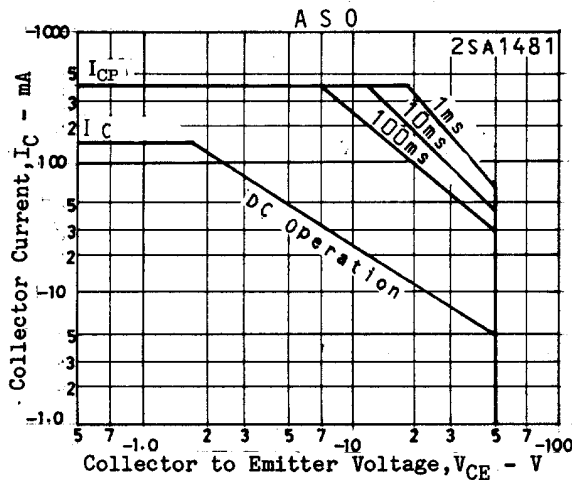
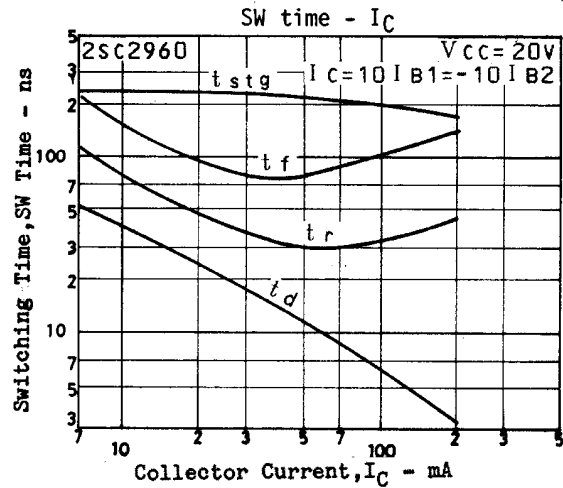
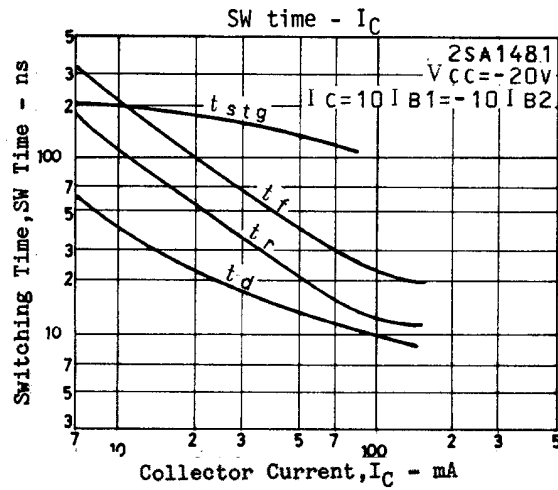
10 IB1 = -10 IB2 = IC = 10mA
Unit (resistance : Ω, capacitance : F)



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